NSN 5961-01-438-7540

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-438-7540 **Inclosure Material:** Metal **Overall Length:** 0.371 inches **Terminal Length:** 1.250 inches **Overall Diameter:** Between 0.205 inches and 0.235 inches **Function For Which Designed:** Transient suppressor Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-13 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 256.0 working peak reverse voltage and 285.0 breakdown voltage, dc **Current Rating Per Characteristic:** 200.00 amperes forward current, average preset **Test Data Document:** 80063-a3167867 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No